

N & P-Channel 40-V (D-S) MOSFET

Features

- Low rDS(on) trench technology
- Low thermal impedance
- Fast switching speed

Typical Applications:

- White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

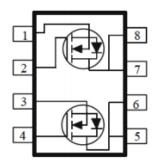
Packing & Order Information

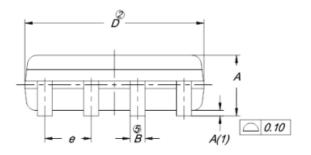
3,000/Reel

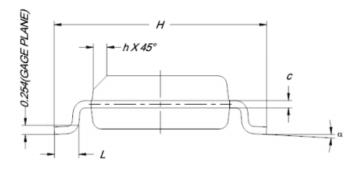




Graphic symbol







-	MILLIMETERS				
DIM.	MIN.	NOM.	MAX.		
А	1.35	1.55	1.75		
A(1)	0.10	0.18	0.25		
В	0.38	0.45	0.51		
С	0.19	0.22	0.25		
D	4.80	4.90	5.00		
E	3.80	3.90	4.00		
е	1.27 BSC				
н	5.80	6.00	6.20		
L	0.50	0.72	0.93		
α	0°	4°	8°		
ħ	0.25	0.38	0.50		



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MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings (T _A =25°C unless otherwise specified)						
Symbol	Parameter	Value	Unit			
V_{DS}	Drain-Source Voltage	40	V			
V _{GS}	Gate-Source Voltage	±20	V			
1	Continuous Drain Current ^a (T _A =25°C)	5.8	A			
ID	Continuous Drain Current ^a (T _A =70°C)	4.5	А			
I _{DM}	Pulsed Drain Current ^b	20	А			
I _S	Continuous Source Current (Diode Conduction) ^a	2.6	A			
P _D	Power Dissipation ^a (T _A =25°C)	2.1	W			
	Power Dissipation ^a (T _A =70°C)	1.3	W			
T _J /T _{STG}	Operating Junction and Storage Temperature	-55 to 150	°C			

Thermal Resistance Ratings						
Symbol	Symbol Parameter Maximum					
$R_{ extsf{ heta}JA}$	Maximum Junction-to-Ambient ^a (t <= 10 sec)	62.5	°C/W			
	Maximum Junction-to-Ambient ^a (Steady-State)	110	0/11			

Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. Pulse width limited by maximum junction temperature

Static						
Symbol	Parameter	Test Conditions	Min	Тур.	Max.	Units
$V_{\text{GS(th)}}$	Gate-Source Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A (N-ch)$	1			
		$V_{DS} = V_{GS}, I_{D} = -250 \mu A \text{ (P-ch)}$	-1			V
I _{GSS}	Gate-Body Leakage	$V_{DS} = 0 V$, $V_{GS} = \pm 20 V$			±100	nA
	Zero Gate Voltage Drain Current	$V_{DS} = 32 V$, $V_{GS} = 0 V$ (N-ch)			1	
I _{DSS}		V_{DS} = -32 V , V_{GS} = 0 V (P-ch)			-1	uA
L	On-State Drain Current	$V_{DS} = 5 \text{ V}, V_{Gs} = 10 \text{ V} (\text{N-ch})$	10			A
I _{D(on)}		$V_{DS} = -5 V, V_{Gs} = -10 V (P-ch)$	-10			
	Drain-Source On-Resistance	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 5.3 \text{ A} (\text{N-ch})$			42	mΩ
r		$V_{GS} = 4.5 \text{ V}, I_{D} = 4.4 \text{ A} (\text{N-ch})$			60	
DS(on)		V_{GS} = -10 V, I_{D} = -3.6 A (N-ch)			90	
		V_{GS} = -4.5 V, I_{D} = -2.6 A (N-ch)			125	
а.	Forward Tranconductance	V_{GS} = 15 V, I_{D} = 5.3 A (N-ch)		13		S
g _{fs}		$V_{GS} = -15 \text{ V}, I_{D} = -3.6 \text{ A} (P-ch)$		11		
V_{SD}	Diode Forward Voltage	$I_{\rm S} = 1.3 \text{ A}$, $V_{\rm GS} = 0 \text{ V}$ (N-ch)		0.77		
		$I_{\rm S}$ = -1.2 A , $V_{\rm GS}$ = 0 V (P-ch)		-0.81		V



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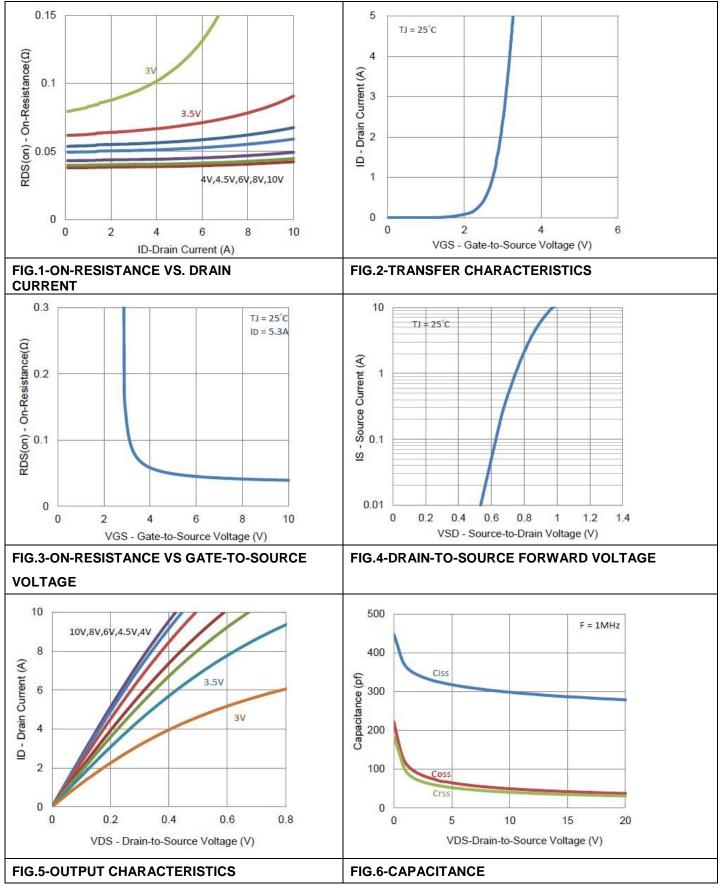
Dynamic ^b						
Symbol	Parameter	Test Conditions	Min	Тур.	Max.	Units
Qg	Total Gate Charge	N-Channel		3.6		nC
Q _{gs}	Gate-Source Charge	$V_{DS} = 20 V$, $I_{D} = 5.3 A$,		1.3		nC
Q _{gd}	Gate-Drain Charge	V _{GS} = 10 V		1.4		nC
t _{d(on)}	Turn-On Delay Time	N-Channel		2		ns
t _r	Rise Time	$I_D = 5.3 \text{ A}$, $R_L = 3.5 \Omega$,		18		ns
t _{d(off)}	Turn-Off Delay Time	V_{GEN} = 10 V , R_{GEN} = 6 Ω		16		ns
tf	Fall Time	V _{DD} = 20 V		5		ns
C _{ISS}	Input Capacitance	N-Channel		287		pF
C _{OSS}	Output Capacitance	V _{DS} = 15 V		42		pF
C _{RSS}	Reverse Transfer Capacitance	$f = 1 MHz$, $V_{GS} = 0 V$		34		pF
Qg	Total Gate Charge	P-Channel		5.8		nC
Q _{gs}	Gate-Source Charge	$V_{DS} = -20 \text{ V}$, $I_{D} = -3.6 \text{ A}$,		1.6		nC
Q _{gd}	Gate-Drain Charge	V _{GS} = -10 V		2.3		nC

Dynamic ^b						
Symbol	Parameter	Test Conditions	Min	Тур.	Max.	Units
t _{d(on)}	Turn-On Delay Time	P-Channel		4		ns
t _r	Rise Time	$I_{\rm D} = -3.6 \text{ A}$, $R_{\rm L} = 5.5 \Omega$,		5		ns
t _{d(off)}	Turn-Off Delay Time	V_{GEN} = -10 V , R_{GEN} = 6 Ω		17		ns
tf	Fall Time	V _{DD} = -20 V		7		ns
C _{ISS}	Input Capacitance	P-Channel		384		pF
C _{OSS}	Output Capacitance	V _{DS} = -15 V		36		pF
C _{RSS}	Reverse Transfer Capacitance	f = 1 MHz ,V _{GS} = 0 V		36		pF



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Typical Electrical Characteristics - N-channel



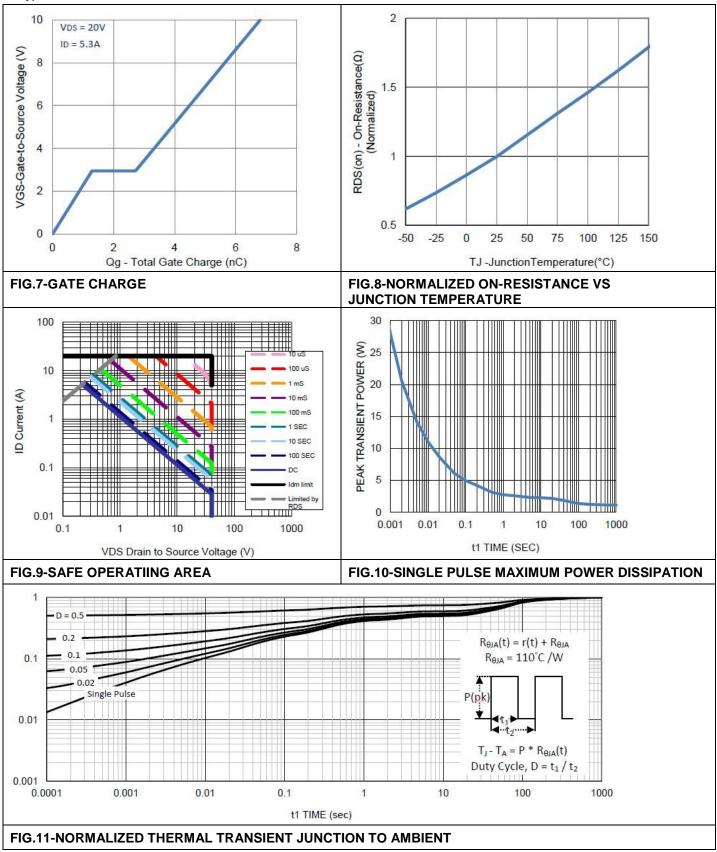


MS4541C N & P-Channel 40-V (D-S) MOSFET



N & P-Channel 40-V (D-S) MOSFET

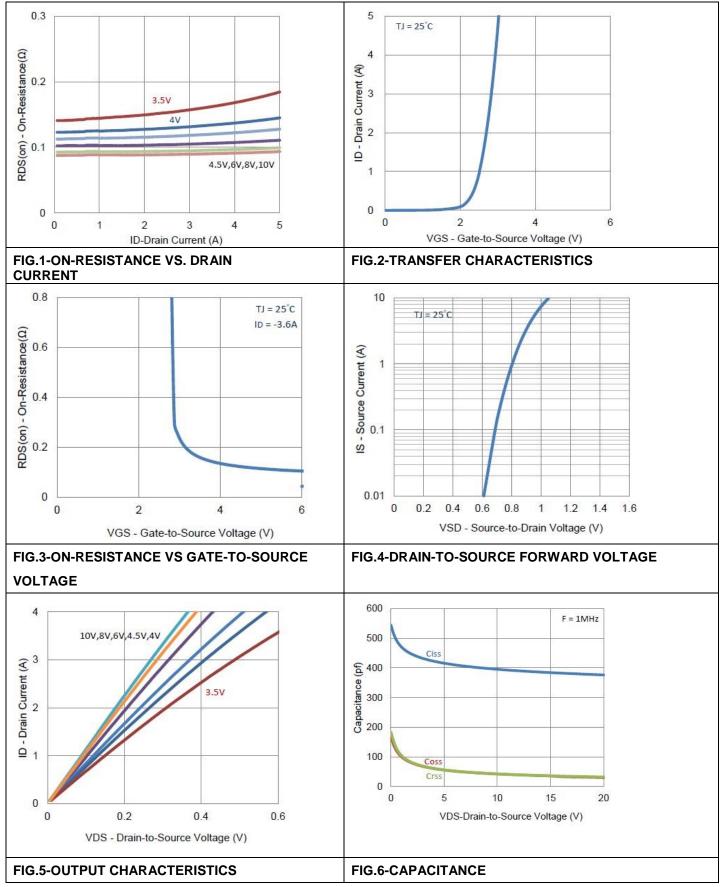
Typical Electrical Characteristics - N-channel





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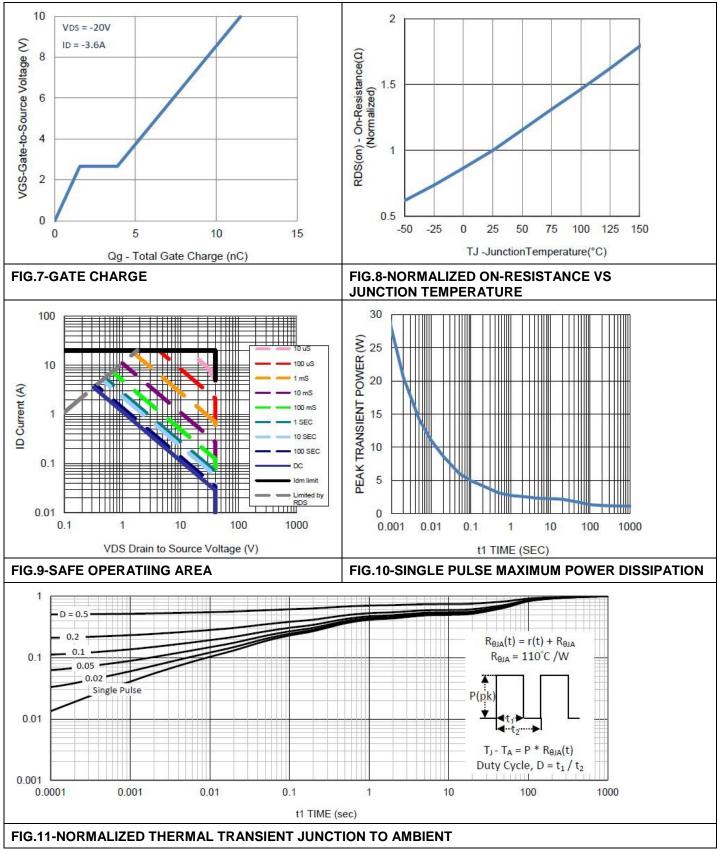
•Typical Electrical Characteristics - P-channel





N & P-Channel 40-V (D-S) MOSFET

Typical Electrical Characteristics - P-channel





N & P-Channel 40-V (D-S) MOSFET

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